· · · · · · · · · · · · · · · · · · ·	Application No.	Applicant(s)
Notice of Allowability	10/717,375	MEARS ET AL.
	Examiner	Art Unit
	Thinh T Nguyen	2818
The MAILING DATE of this communication appeal All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT R	(OR REMAINS) CLOSED in this or other appropriate communica IGHTS. This application is subjection	application. If not included tion will be mailed in due course. THIS
1. This communication is responsive to <u>11/19/2003</u> .		
2. The allowed claim(s) is/are 72-97.		
3. \boxtimes The drawings filed on <u>19 November 2003</u> are accepted by	the Examiner.	
 4. Acknowledgment is made of a claim for foreign priority ur a) All b) Some* c) None of the: 1. Certified copies of the priority documents have 2. Certified copies of the priority documents have 3. Copies of the certified copies of the priority do International Bureau (PCT Rule 17.2(a)). * Certified copies not received: 	been received. been received in Application No	·
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONN THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		ply complying with the requirements
5. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which give		
6. ☐ CORRECTED DRAWINGS (as "replacement sheets") mus (a) ☐ including changes required by the Notice of Draftspers 1) ☐ hereto or 2) ☐ to Paper No./Mail Date (b) ☐ including changes required by the attached Examiner's Paper No./Mail Date Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in to 7. ☐ DEPOSIT OF and/or INFORMATION about the depo	con's Patent Drawing Review (Posteria). S Amendment / Comment or in the second secon	e Office action of awings in the front (not the back) of 21(d).
attached Examiner's comment regarding REQUIREMENT		
Attachment(s) 1. ☑ Notice of References Cited (PTO-892)	5. Notice of Informa	al Patent Application (PTO-152)
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	6.	
3. Information Disclosure Statements (PTO-1449 or PTO/SB/0	8), 7. ☐ Examiner's Ame	
Paper No./Mail Date 4. Examiner's Comment Regarding Requirement for Deposit	8. 🛭 Examiner's State	ement of Reasons for Allowance
of Biological Material	9. 🗌 Other	
David Nelms Supervisory Patent Examiner Technology Center 2800		

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DETAILED ACTION

Specification

1. The specification has been checked to the extent necessary to determine the presence of all possible minor errors. However, the applicant cooperation is requested in correcting any errors of which the applicant may become aware in the specification.

Reason for allowance

2. Claims 72-97 are allowed. The following is an examiner's statement of reason for allowance:

I/ Group I: Claims 72-87:

None of the references of record teaches or suggests the claimed **SEMICONDUCTOR DEVICE INCLUDING BAND-ENGINEERED SUPERLATTICE** having the limitations:

-- "each group of layers of said superlattice comprising four stacked base semiconductor monolayers defining a base semiconductor portion and an energy band-modifying layer thereon; said energy-band modifying layer comprising at least one non-semiconductor monolayer constrained within a crystal lattice of adjacent base semiconductor portions. "-- and all other limitations as recited in claim 72.

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II/ Group II: Claims 88-97:

None of the references of record teaches or suggests the claimed **SEMICONDUCTOR DEVICE INCLUDING BAND-ENGINEERED SUPERLATTICE** having the limitations:

-- " each group of layers of said superlattice comprising four stacked base silicon monolayers defining a base semiconductor portion and an energy band-modifying layer thereon; said energy-band modifying layer comprising at least one oxygen monolayer constrained within a crystal lattice of adjacent base semiconductor portions. "--

and all other limitations as recited in claim 88.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance".

Conclusion

3. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure: Mori et al. (US patent 5,705,408) disclose a Method for forming semiconductor integrated circuit using monolayer epitaxial growth

4. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thinh T Nguyen whose telephone number is 571-272-1790. The examiner can normally be reached on Monday-Friday 9:00am-6:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David Nelms can be reached at 571-272-1787. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 872-9306 for regular communications and (703) 872-9319 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

Thinh T Nguyen TNV

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David Nelms Supervisory Patent Examiner Technology Center 2800